

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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KSC5020

High Voltage, High Quality

- High Speed Switching : t_F=0.1μs
- Wide SOA



1.Base 2.Collector 3.Emitter

NPN Silicon Transistor

Absolute Maximum Ratings $T_C=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	800	V
V _{CEO}	Collector-Emitter Voltage	500	V
V _{EBO}	Emitter-Base Voltage	7	V
I _C	Collector Current (DC)	3	Α
I _{CP}	Collector Current (Pulse)	6	Α
I _B	Base Current (DC)	1	Α
P _C	Collector Dissipation (T _C =25°C)	40	W
TJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature	- 55 ~ 150	°C

Electrical Characteristics $T_C=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	$I_C = 1 \text{mA}, I_E = 0$	800			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_C = 5mA, I_B = 0$	500			V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_E = 1 \text{mA}, I_C = 0$	7			V
V _{CEX} (sus)	Collector-Emitter Sustaining Voltage	$I_C = 1.5A$, $I_{B1} = -I_{B2} = 0.6A$ L = 2mH, Clamped	500			V
I _{CBO}	Collector Cut-off Current	$V_{CB} = 500V, I_{E} = 0$			10	μА
I _{EBO}	Emitter Cut-off Current	$V_{EB} = 5V, I_{C} = 0$			10	μА
h _{FE1}	DC Current Gain	$V_{CE} = 5V, I_{C} = 0.3A$	15		50	
h _{FE2}		$V_{CE} = 5V, I_{C} = 1.5A$	8			
V _{CE} (sat)	Collector-Emitter Saturation Voltage	$I_C = 1.5A, I_B = 0.3A$			1	V
V _{BE} (sat)	Base-Emitter Saturation Voltage	$I_C = 1.5A, I_B = 0.3A$			1.5	V
C _{ob}	Output Capacitance	V _{CB} = 10V, f = 1MHz		50		pF
f _T	Current Gain Bandwidth Product	$V_{CE} = 10V, I_{C} = 0.3A$		18		MHz
t _{ON}	Turn On Time	V _{CC} = 200V			0.5	μs
t _{STG}	Storage Time	$I_{C}=5I_{B1}=-2.5I_{B2}=2A$			3	μs
t _F	Fall Time	$R_L = 100\Omega$			0.3	μs

h_{FE} Classification

Classification	R	0	Υ
h _{FE1}	15 ~ 30	20 ~ 40	30 ~ 50

Typical Characteristics

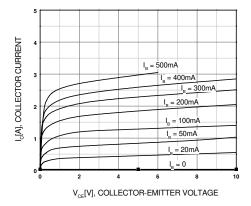


Figure 1. Static Characteristic

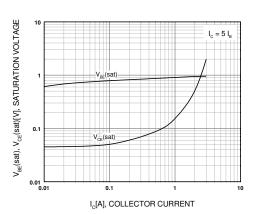


Figure 3. Collector-Emitter Saturation Voltage Base-Emitter Saturation Voltage

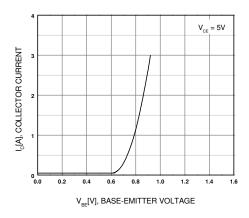


Figure 5. Base-Emitter On Voltage

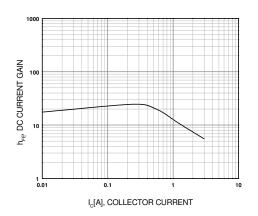


Figure 2. DC current Gain

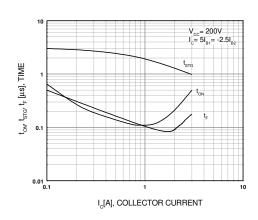


Figure 4. Turn On, Storage and Fall Time vs. Collector Current

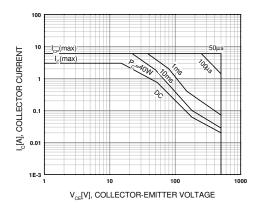


Figure 6. Forward Bias Safe Operating Area

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Typical Characteristics (Continued)

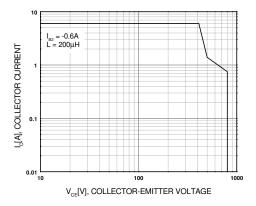


Figure 7. Reverse Bias Safe Operating Area

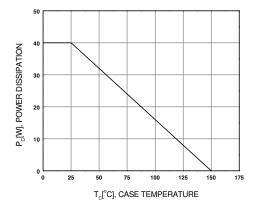
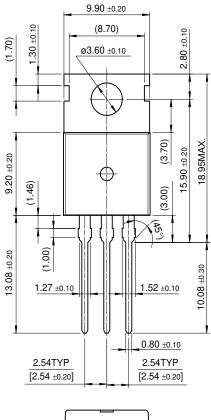
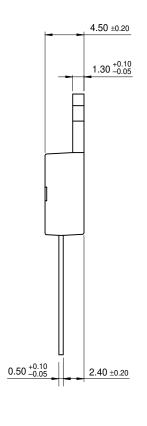


Figure 8. Power Derating

Package Dimensions

TO-220





10.00 ±0.20

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CROSSVOLT™	FRFET™	MicroPak™	QFET™	SuperSOT™-8
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EcoSPARK™	GTO™	MSX™	QT Optoelectronics™	TinyLogic™
E ² CMOS™	HiSeC™	MSXPro™	Quiet Series™	TruTranslation™
EnSigna™	I ² C TM	OCXTM	RapidConfigure™	UHC™
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Programmable Active Droop™		OPTOPLANAR™	SMART START™	

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